TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

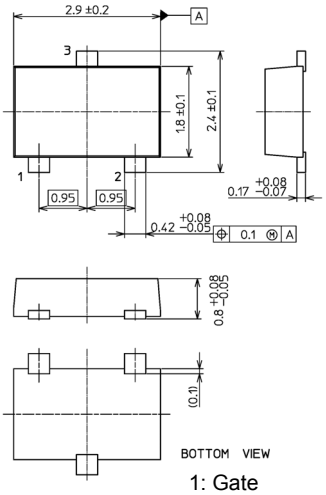
SSM3K329R

○ Power Management Switch Applications

○ High-Speed Switching Applications

- 1.8-V drive
- Low ON-resistance: $R_{DS(ON)}$ = 289 mΩ (max) (@V_{GS} = 1.8 V)
  : $R_{DS(ON)}$ = 170 mΩ (max) (@V_{GS} = 2.5 V)
  : $R_{DS(ON)}$ = 126 mΩ (max) (@V_{GS} = 4.0 V)

Unit: mm



1: Gate
2: Source
3: Drain

SOT-23F

JEDEC	―
JEITA	―
TOSHIBA	2-3Z1A

Weight: 11 mg (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	30	V
Gate-source voltage		V_{GSS}	±12	V
Drain current	DC	I_D (Note 1)	3.5	A
	Pulse	I_{DP} (Note 1)	7.0	
Power dissipation		P_D (Note 2)	1	W
		t = 10s	2	
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: The channel temperature should not exceed 150°C during use.

Note 2: Mounted on a FR4 board.
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm^2)

Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance $R_{th\ (ch\text{-}a)}$ and Power dissipation P_D vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration

Start of commercial production
2010-02

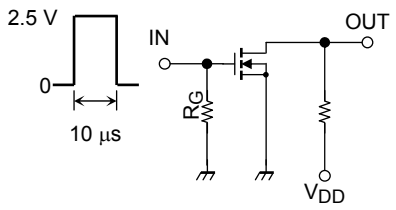
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-source breakdown voltage		$V_{(BR)\ DSS}$	I_D = 1 mA, V_{GS} = 0 V	30	—	—	V
		$V_{(BR)\ DSX}$	I_D = 1 mA, V_{GS} = −12 V	18	—	—	
Drain cut-off current		I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V	—	—	1	μA
Gate leakage current		I_{GSS}	V_{GS} = ± 12 V, V_{DS} = 0 V	—	—	±1	μA
Gate threshold voltage		V_{th}	V_{DS} = 3 V, I_D = 1 mA	0.4	—	1.0	V
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = 3 V, I_D = 1.0 A (Note 3)	2.1	4.2	—	S
Drain–source ON-resistance		$R_{DS\ (ON)}$	I_D = 1.0 A, V_{GS} = 4.0 V (Note 3)	—	96	126	mΩ
			I_D = 0.8 A, V_{GS} = 2.5 V (Note 3)	—	118	170	
			I_D = 0.5 A, V_{GS} = 1.8 V (Note 3)	—	158	289	
Input capacitance		C_{iss}	V_{DS} = 15V, V_{GS} = 0 V, f = 1 MHz	—	123	—	pF
Output capacitance		C_{oss}		—	43	—	
Reverse transfer capacitance		C_{rss}		—	18	—	
Total gate charge		Q_g	V_{DS} = 15V, I_D = 2.0 A V_{GS} = 4 V	—	1.5	—	nC
Gate-source charge		Q_{gs1}		—	0.3	—	
Gate-drain charge		Q_{gd}		—	0.6	—	
Switching time	Turn-on time	t_{on}	V_{DD} = 15 V, I_D = 1.0 A, V_{GS} = 0 to 2.5 V, R_G = 4.7 Ω	—	9.2	—	ns
	Turn-off time	t_{off}		—	6.4	—	
Drain-source forward voltage		V_{DSF}	I_D = -3.5 A, V_{GS} = 0 V (Note 3)	—	-0.90	-1.2	V

Note 3: Pulse test

Switching Time Test Circuit

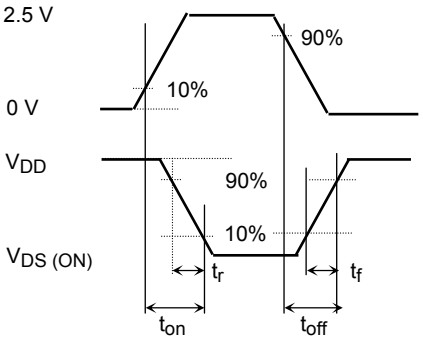
(a) Test Circuit



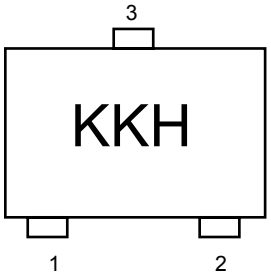
V_{DD} = 15 V
R_G = 4.7 Ω
Duty ≤ 1%
V_{IN}: t_r, t_f < 5 ns
Common Source
Ta = 25°C

(b) V_{IN}

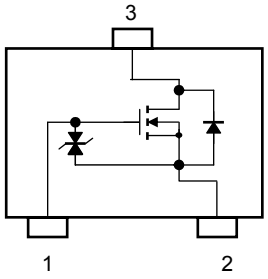
(c) V_{OUT}



Marking



Equivalent Circuit (top view)

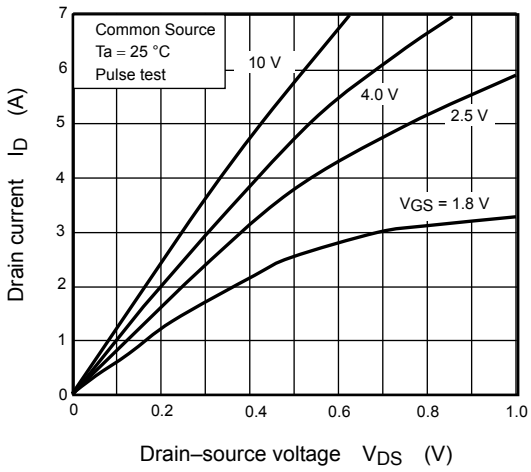


Usage Considerations

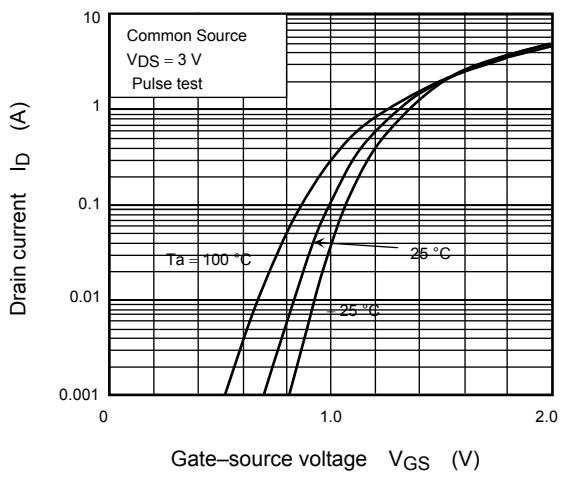
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the SSM3K329R). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th}, and $V_{GS(off)}$ must be lower than V_{th}. This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

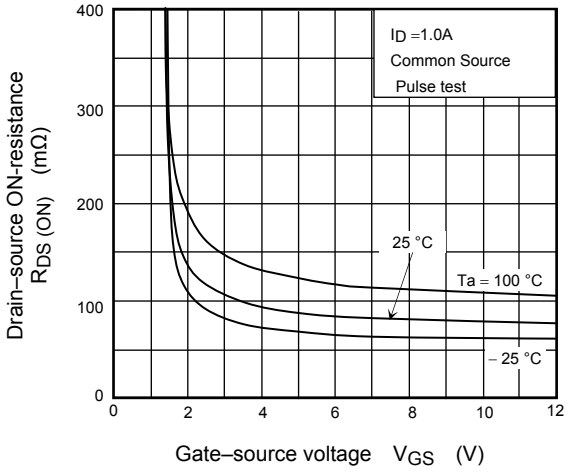
$I_D - V_{DS}$



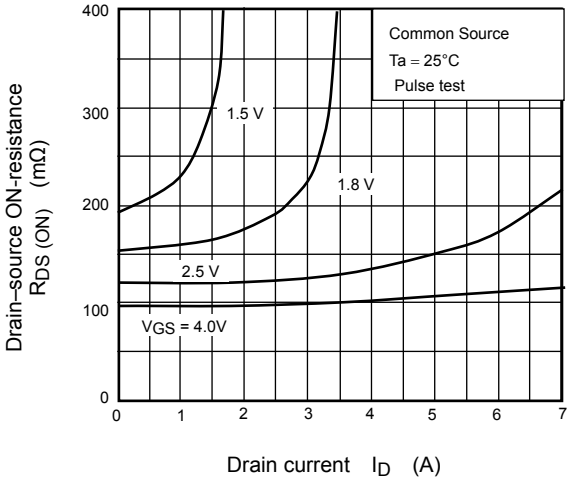
$I_D - V_{GS}$



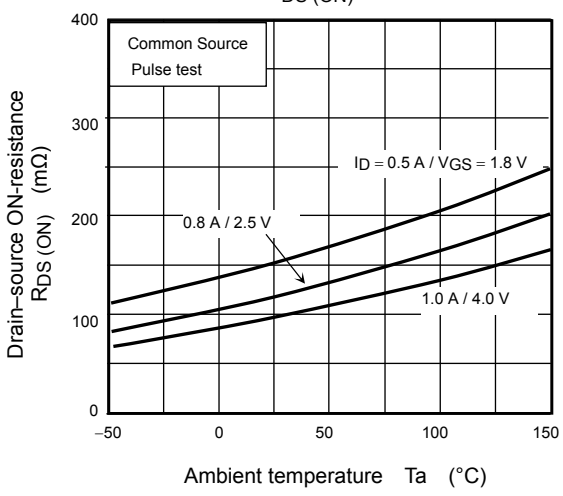
$R_{DS\ (ON)} - V_{GS}$



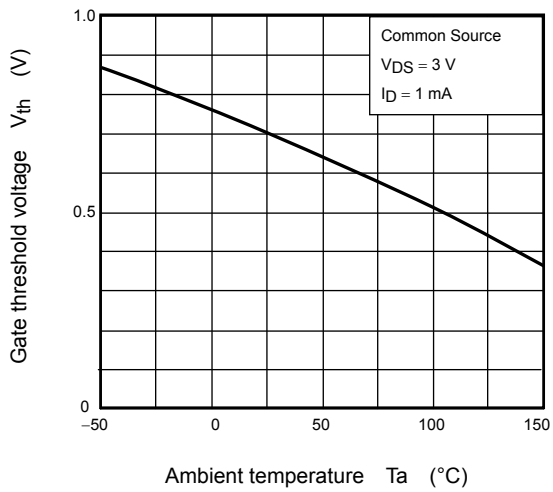
$R_{DS\ (ON)} - I_D$



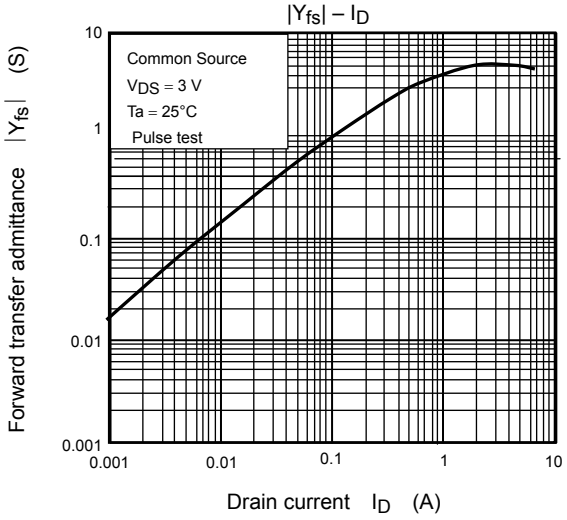
$R_{DS\ (ON)} - Ta$



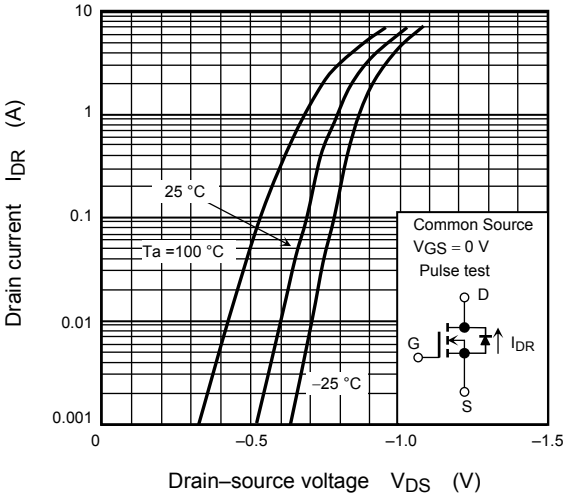
$V_{th} - Ta$



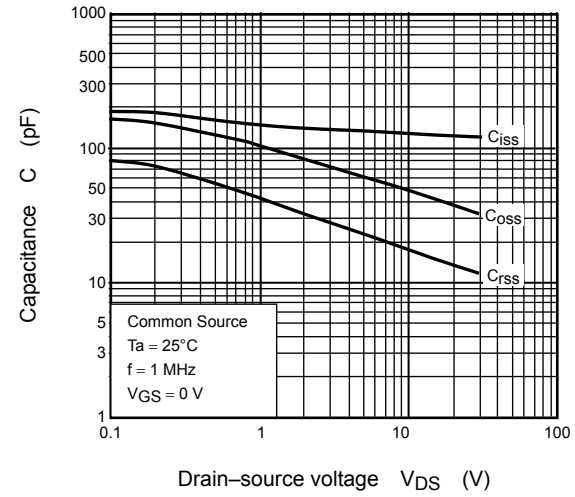
$|Y_{fs}| - I_D$



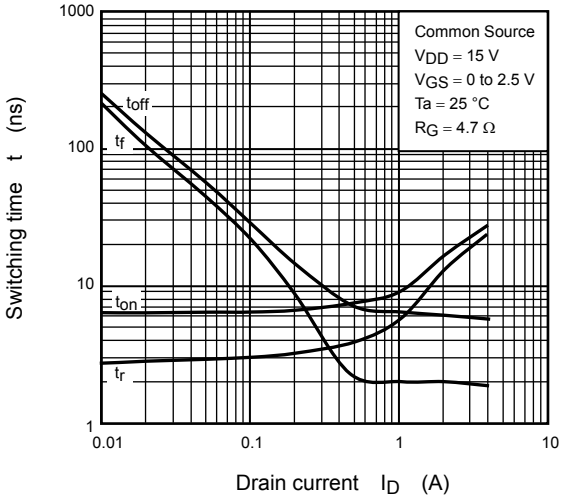
$I_{DR} - V_{DS}$



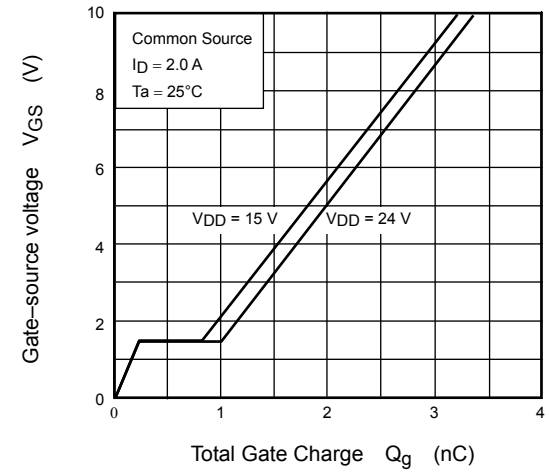
$C - V_{DS}$



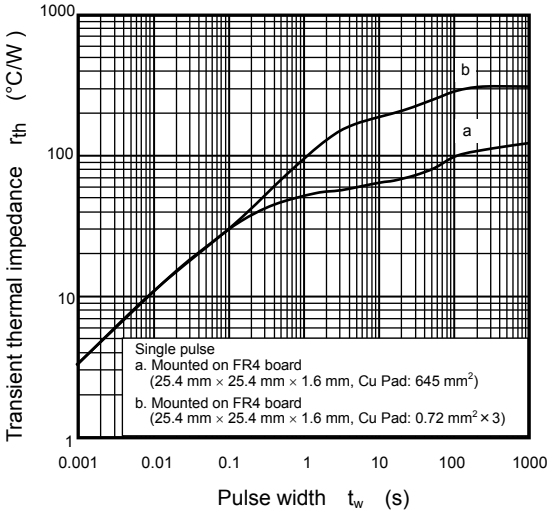
$t - I_D$



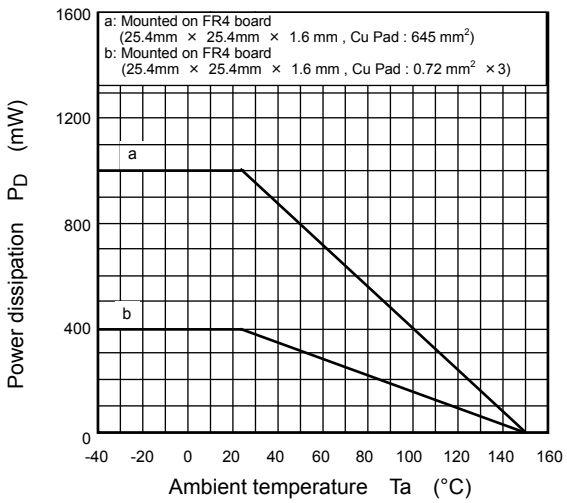
Dynamic Input Characteristic



$r_{th} - t_w$


1000
100
10
1
Transient thermal impedance r_{th} (°C/W)
b
a
Single pulse
a. Mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm²)
b. Mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 0.72 mm² × 3)
0.001
0.01
0.1
1
10
100
1000
Pulse width t_w (s)

$P_D - Ta$


a: Mounted on FR4 board
(25.4mm × 25.4mm × 1.6 mm , Cu Pad : 645 mm²)
b: Mounted on FR4 board
(25.4mm × 25.4mm × 1.6 mm , Cu Pad : 0.72 mm² × 3)
1600
1200
800
400
0
Power dissipation P_D (mW)
a
b
-40
-20
0
20
40
60
80
100
120
140
160
Ambient temperature Ta (°C)

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